## **Experiment 1**

## **MOS IV Characteristics**

- 1. For an NMOS transistor, study the transfer characteristics, i.e. variation of  $I_D$  with  $V_{GS}$ , for a constant  $V_{DS}$ . Obtain the threshold voltage  $V_{th}$  from this characteristic.
- 2. Repeat (1) for multiple values of  $V_{DS}$ .
- 3. For an NMOS transistor, study the output characteristics, i.e. variation of  $I_D$  with  $V_{DS}$ , for a constant  $V_{GS}$ . Comment on your observations from the characteristics.
- 4. Repeat (3) for multiple values of  $V_{GS}$ .
- 5. Repeat (1-4) for a PMOS transistor.